

Conventional Multiferroics and its modification: a case of BiMnO_3

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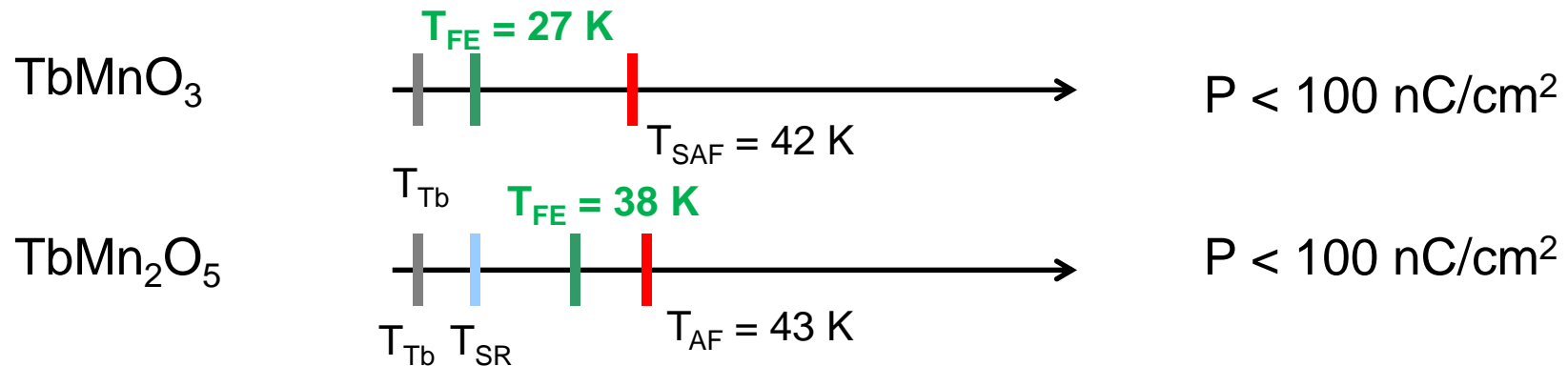
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This work was part of C.-H. Yang's thesis project.

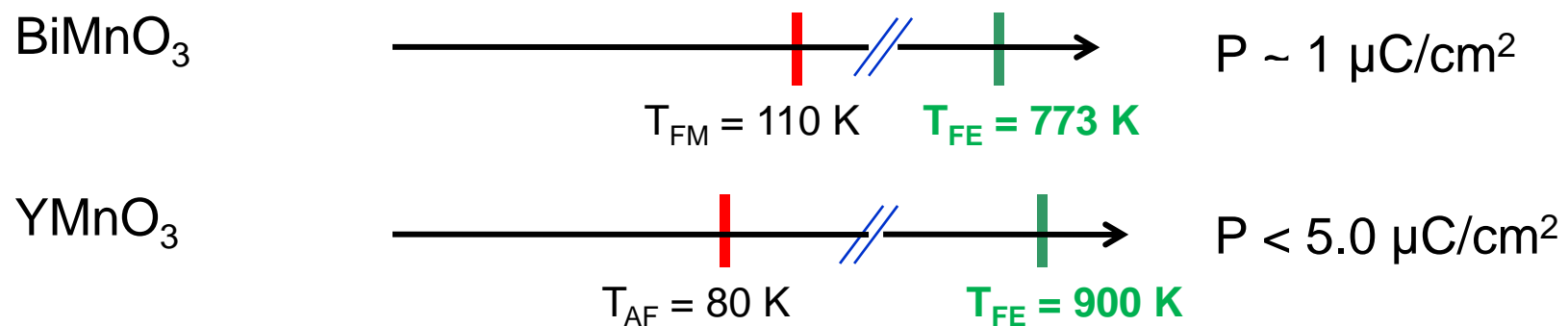
- "Orbital ordering and enhanced magnetic frustration of BiMnO₃ thin films", C.-H. Yang et al., Europhys. Lett. (2006).
- "Resonant x-ray scattering study on multiferroic BiMnO₃", C.-H. Yang et al., Phys. Rev. B (2006)
- "Dynamically enhanced magnetodielectric effect and magnetic field controlled electric relaxations in modified BiMnO₃", C.-H. Yang et al., Phys. Rev. Lett. Submitted (2007)
- "Exchange bias effects for inducing magnetoelectric coupling in a nanoscale composite of MnFe₂O₄ and Mn-doped BiFeO₃", C.-H. Yang et al., Appl. Phys. Lett. In press (2007)

Multiferroics

Magnetically induced Ferroelectrics

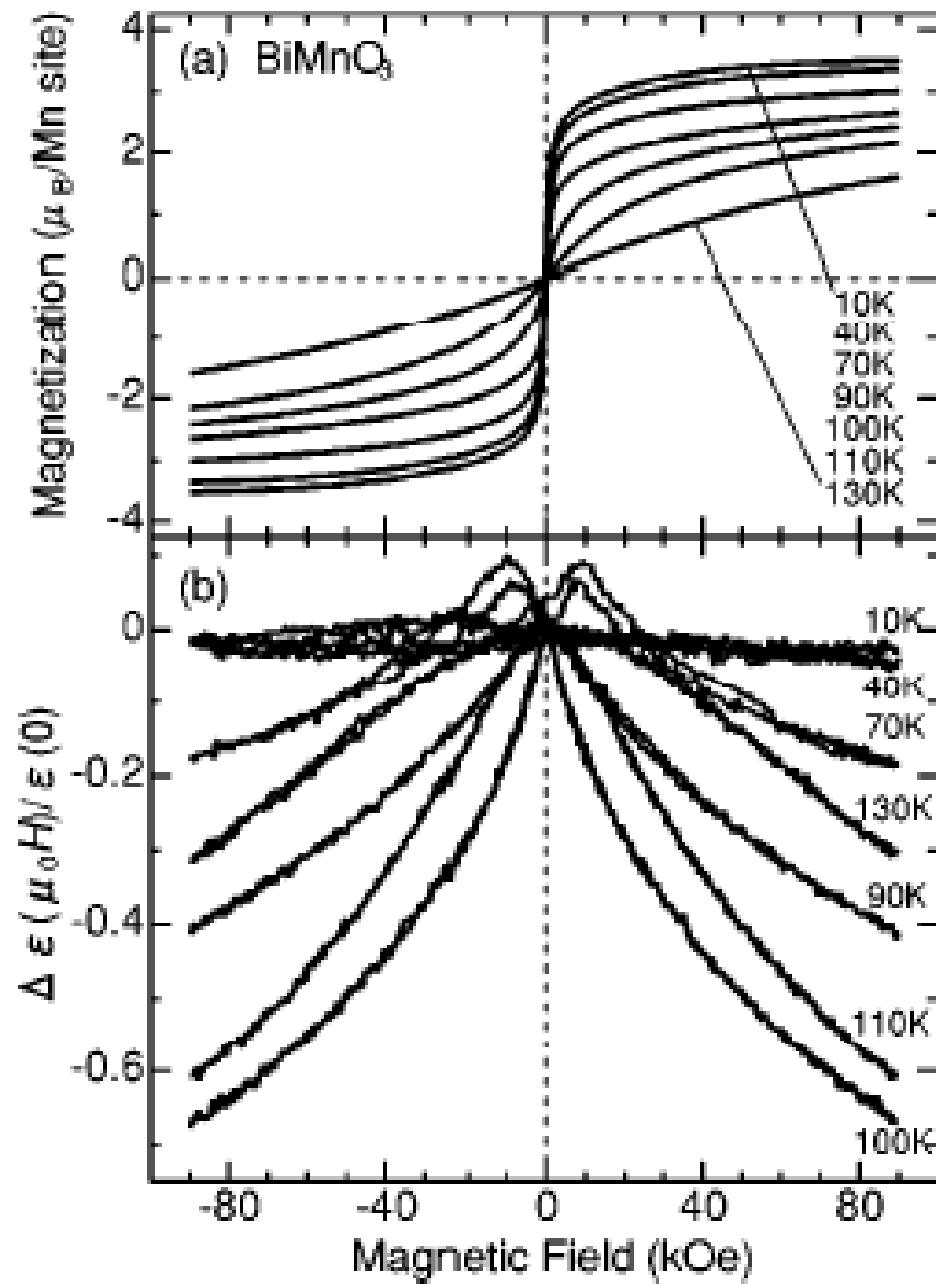


Conventional magnetic Ferroelectrics



Characteristics of conventional multiferroics

- **strong disparity in ferroelectric T_c and magnetic T_c**
- **weak coupling between the electric and magnetic degrees of freedom**



Less than -0.6 % at 10 T

Kimura (2003)

General features of 2nd order Phase transitions

(1) Susceptibility becomes large in the vicinity of the transition point.

An overlap of the two transitions would result in amplification of the mutual coupling, albeit intrinsically small, and thus if one can force an overlap in a material with high T_c 's, one may get strong effects at room temperature.

(2) Two transitions of different origins (weak or no coupling) cannot occur at the same temperature except by accident.

Critical regions associated with pure transitions are usually narrow.

Thus inducing two transitions of different origins to overlap in temperature may not be a simple matter.

***“Disorder”* can control transition temp and also broaden phase transitions.**

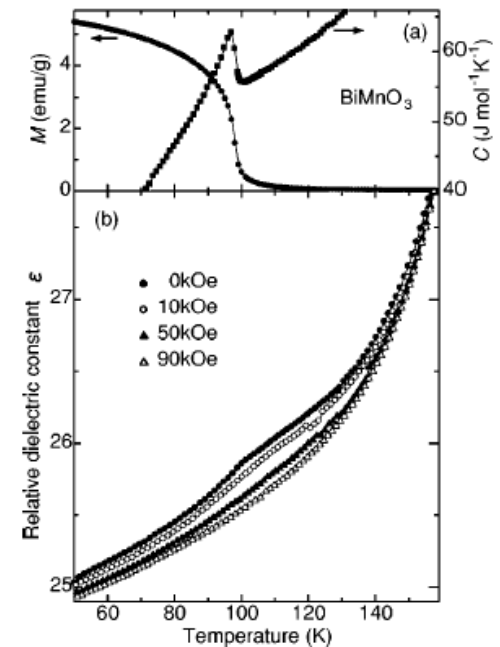
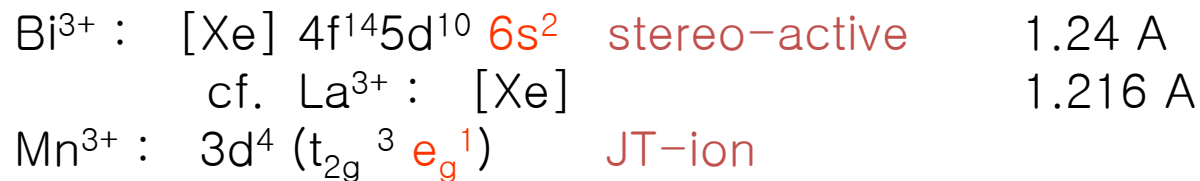
BiMnO₃

BiMnO₃ is a **conventional** multiferroic material.

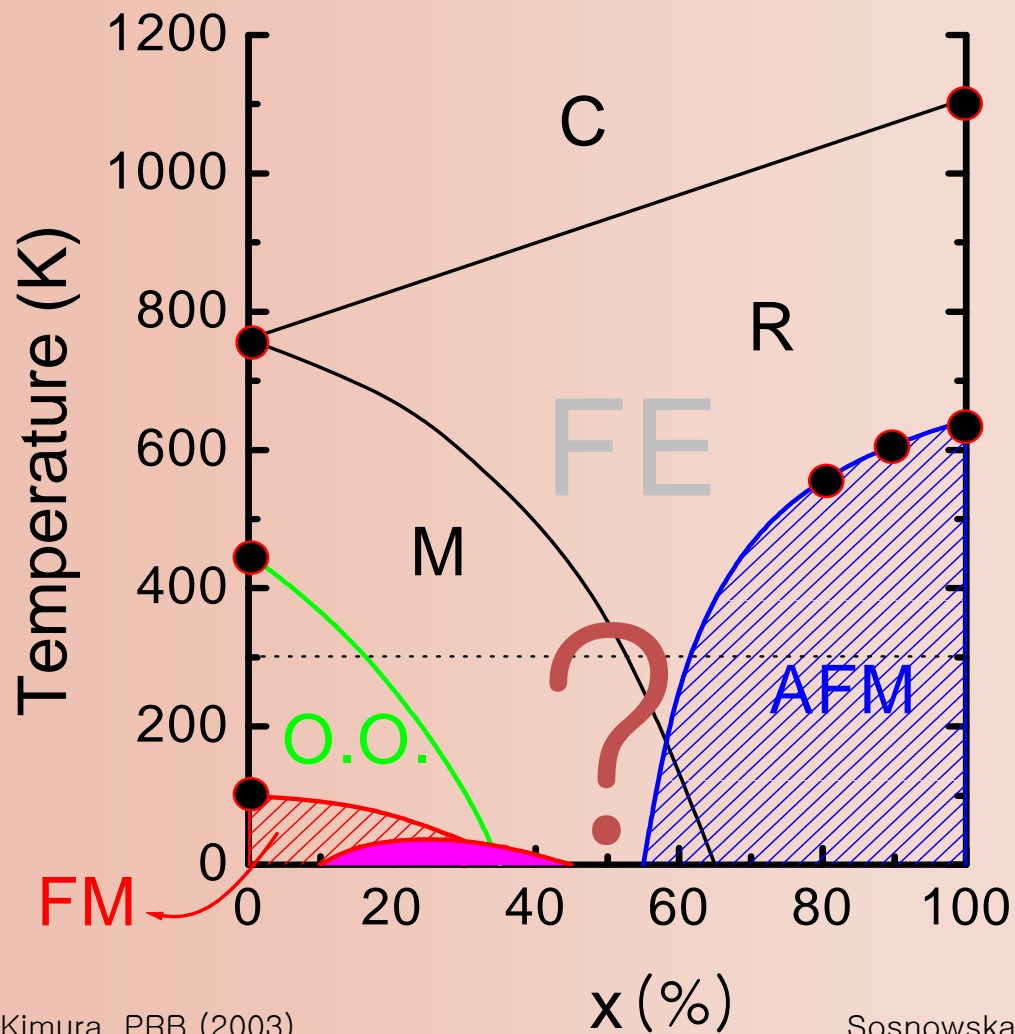
- highly distorted perovskite (monoclinic space group C2)
- a rare ferromagnetic due to Mn³⁺ ions: T_{FM} = 105 K , M = 3.6 μ_B
- ferroelectric due to stereoactive Bi³⁺:

$$T_{FE} = 750\sim 770 \text{ K} , P = 0.1 \mu\text{C}/\text{cm}^2$$

- weak coupling between E & M components



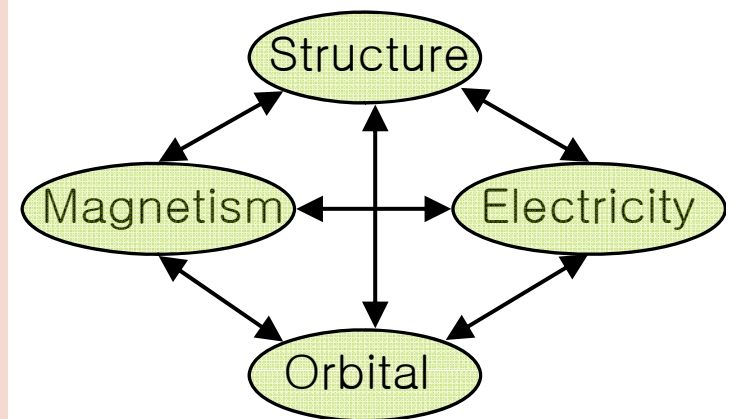
BiMn_{1-x}Fe_xO₃ Phase diagram (추정)



Kimura, PRB (2003)

Sosnowska, Physica B(2002)

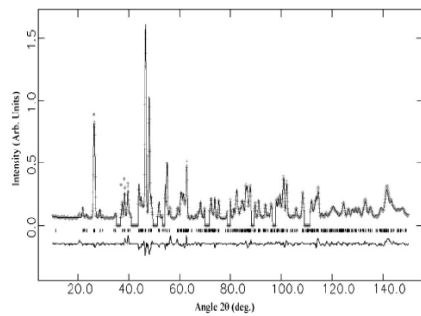
- Ferroelectricity
- Ferromagnetism
- Antiferromagnetism
- Competing ground states
- Structural transition
- Orbital Ordering
- Dilute Jahn–Teller effect



Multiferroic BiMnO_3

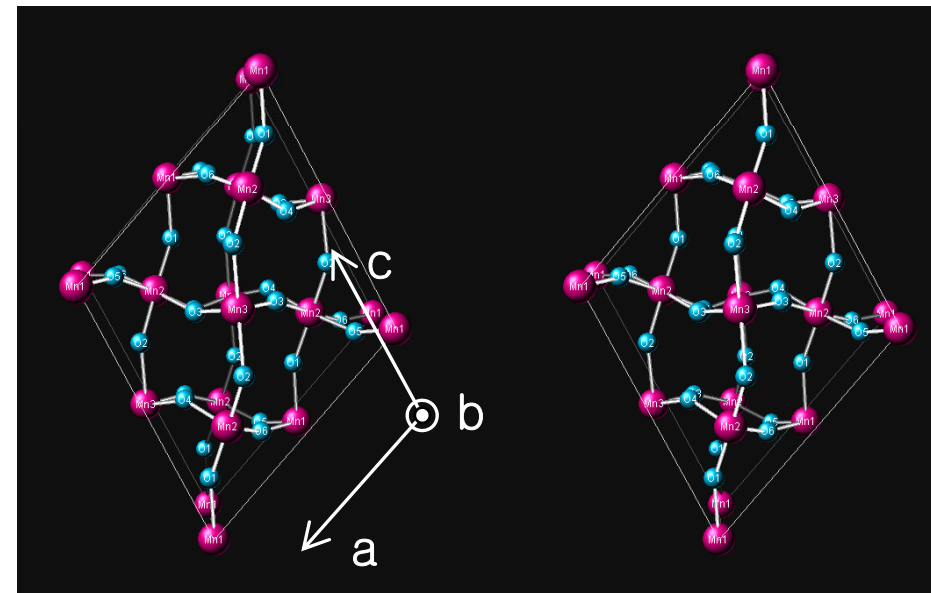
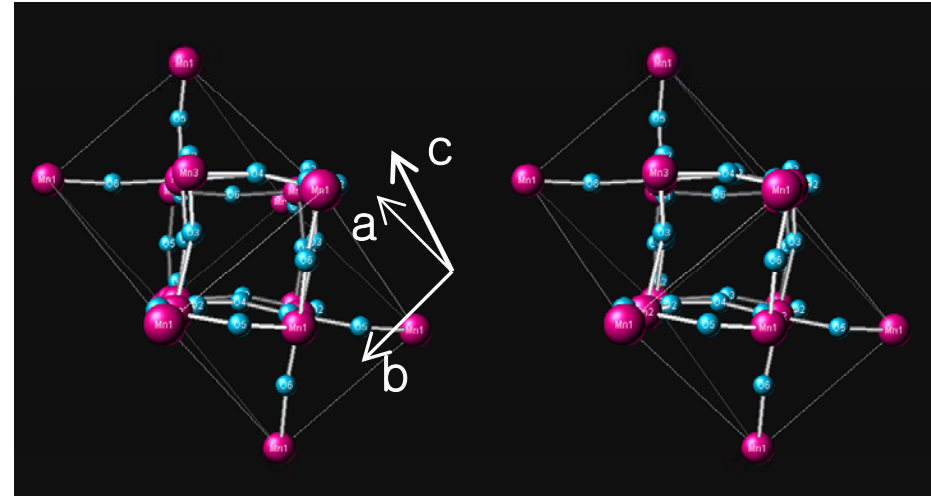
distorted perovskite

*Neutron powder diffraction
Structure Refinement*



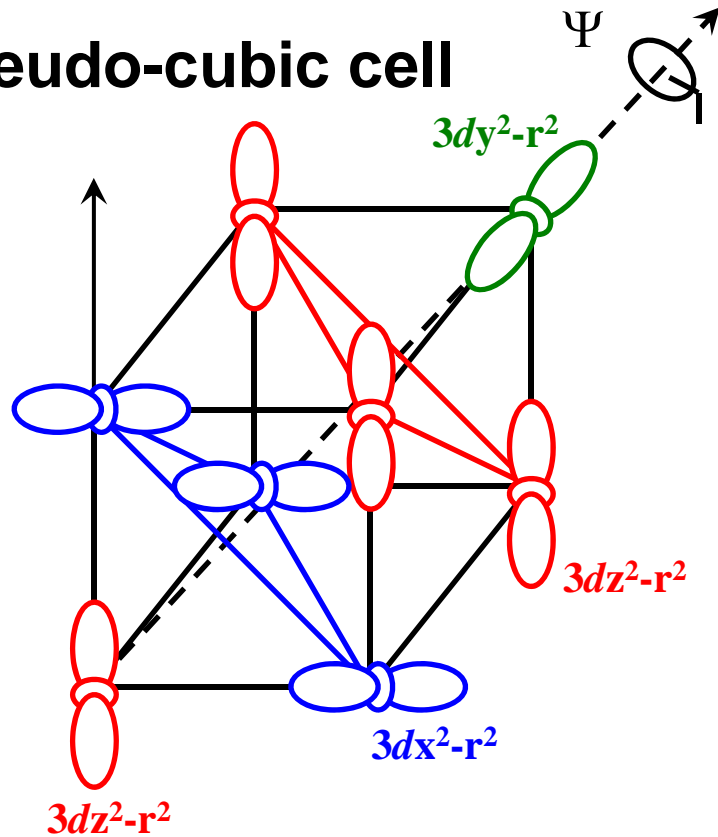
A. M. Santos, C. N. R. Rao *et al.*

Space group :
C2 (monoclinic)

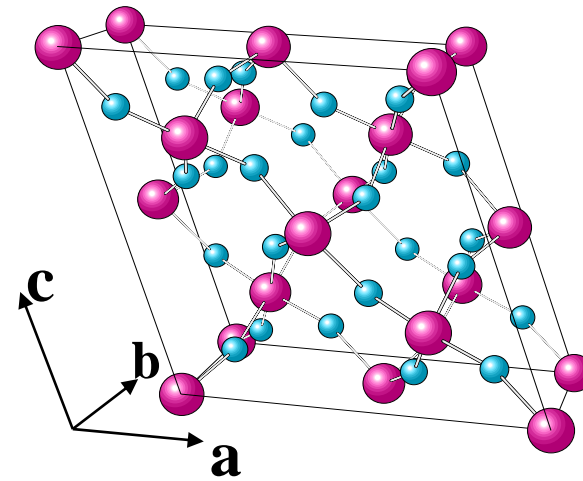


The unit cell of BiMnO_3 and Mn 3d e_g orbitals

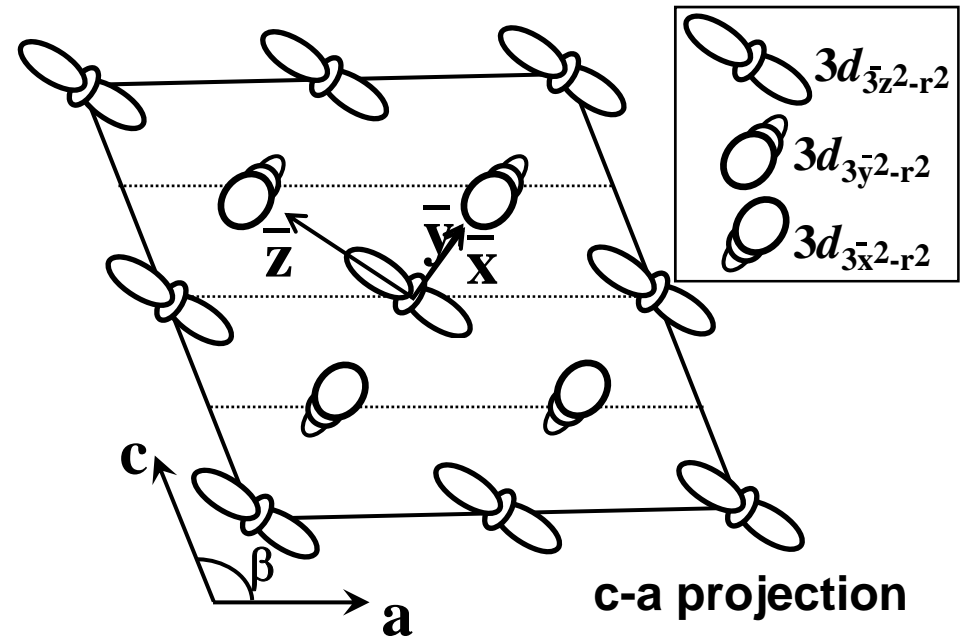
Pseudo-cubic cell



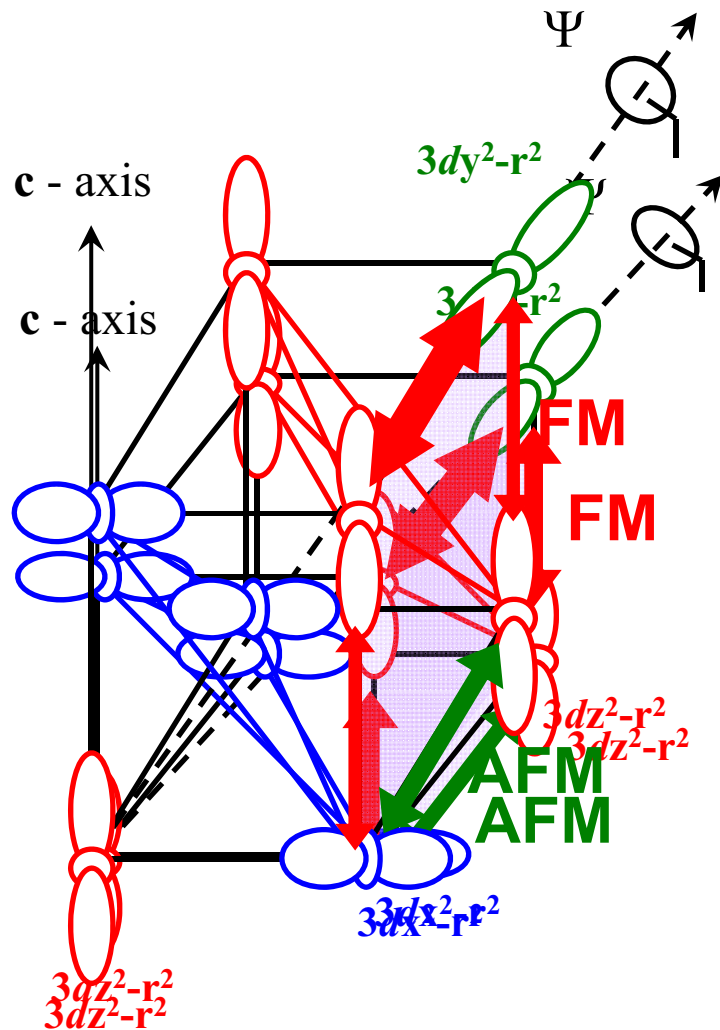
$(\frac{1}{4} \frac{1}{4} \frac{1}{4})$ superstructure modulation is expected due to orbital ordering



Monoclinic cell



**Orbital ordering and magnetic frustration:
two issues addressed with thin films**



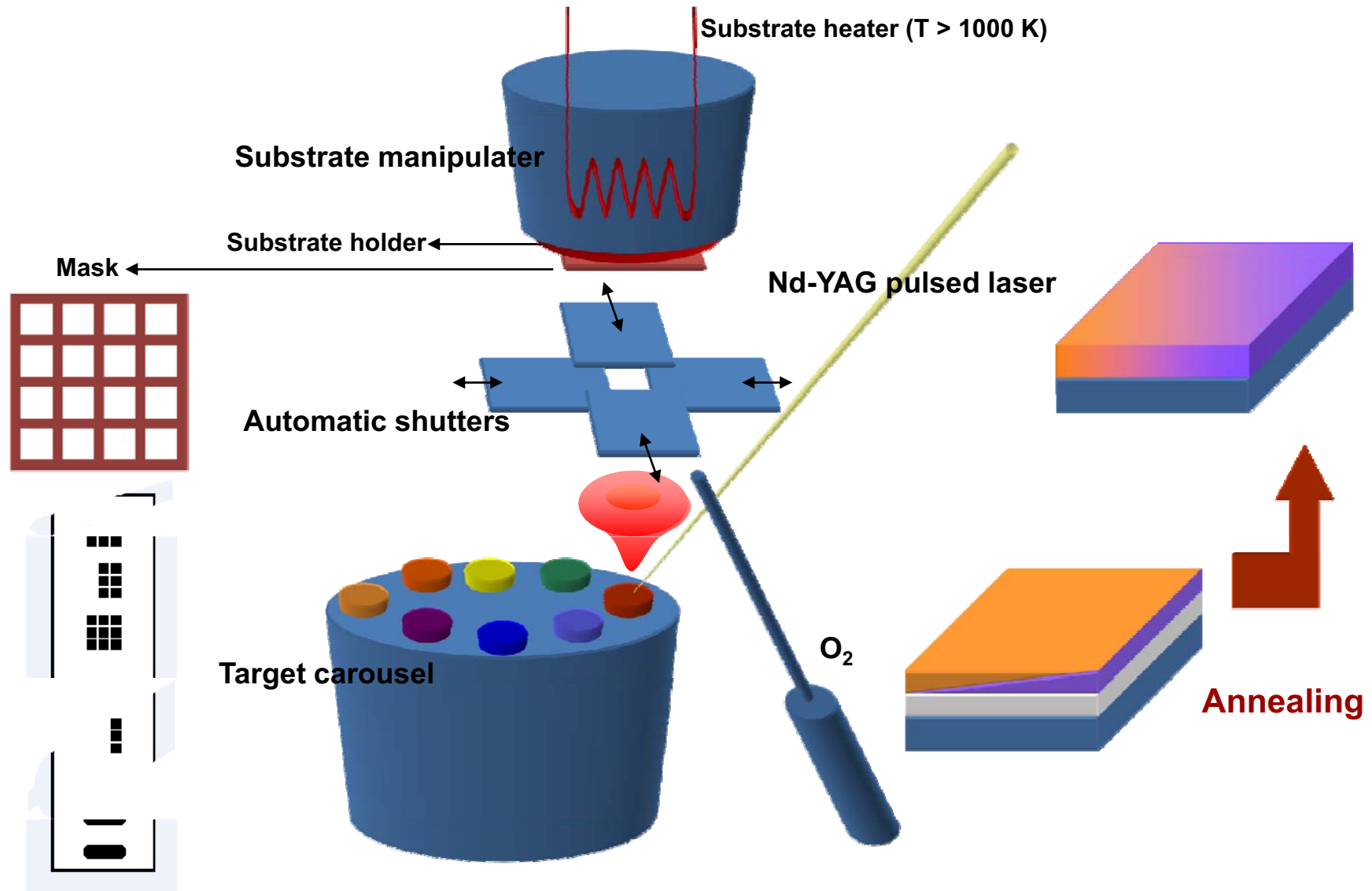
Q#1 ($\frac{1}{4} \frac{1}{4} \frac{1}{4}$) superstructure ?

~ superstructure modulation in
RXS

Q#2 magnetic frustration

Could it be enhanced with
strain in thin films ?

Making thin film samples



Fabrication – BiMnO₃ film

Different thickness of films are grown on SrTiO₃(001)&(111) substrates epitaxially.

Thin one 40 nm ; Thick one 70 nm

Pulsed Laser Deposition
(PLD)

Base pressure 5×10^{-9} torr

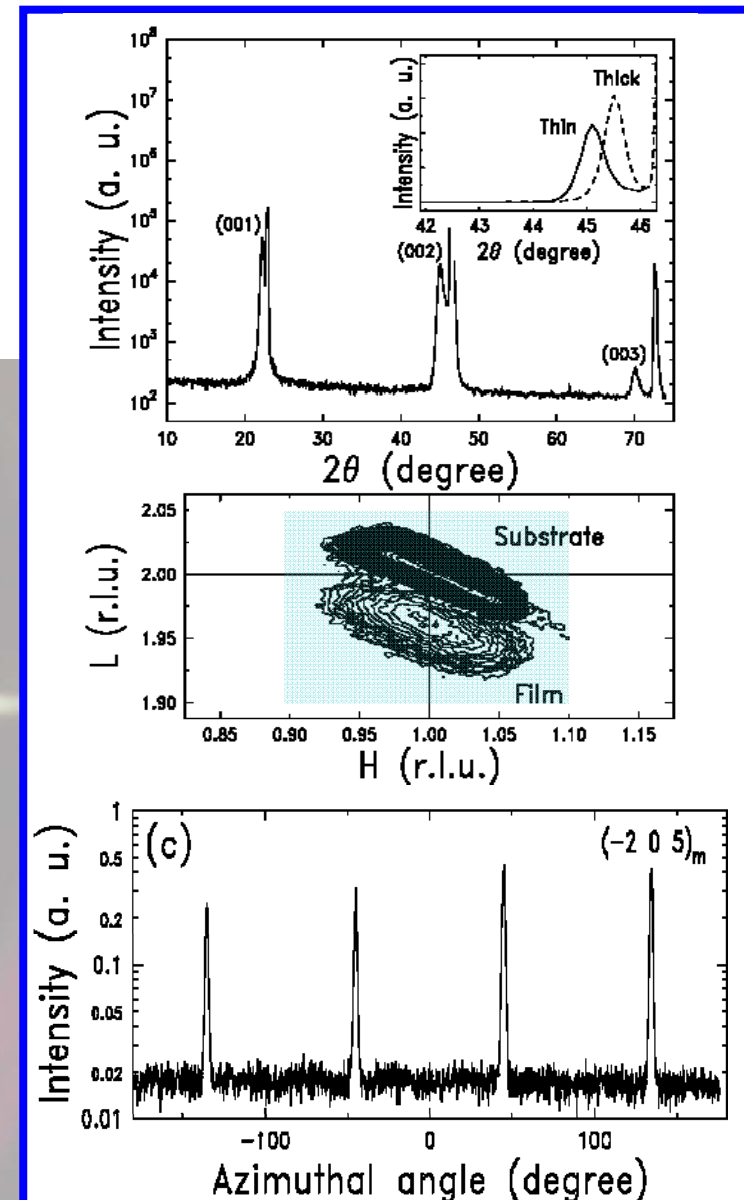
Nd-YAG Laser (266 nm)

fluence 2 J/cm^2

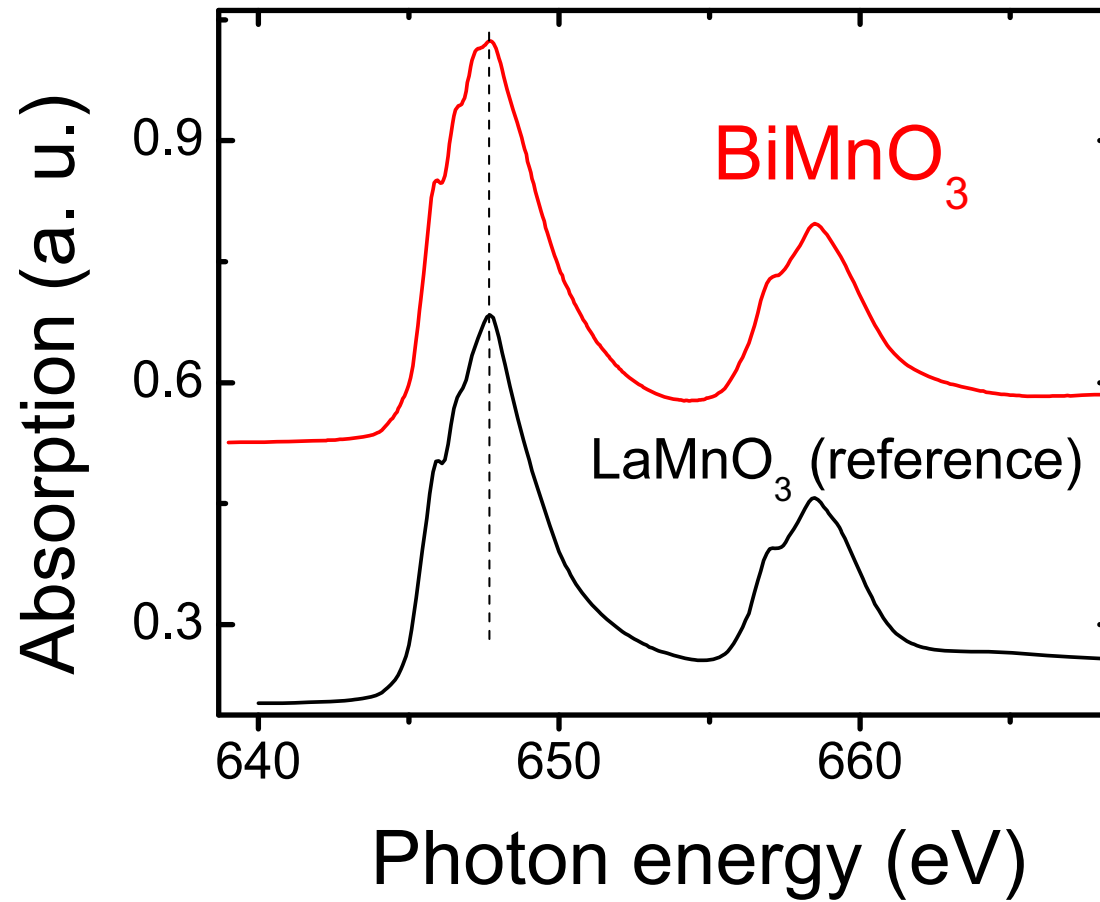
Growing temperature $460 \text{ }^\circ\text{C}$

Oxygen pressure 4 mtorr

Typical growing speed 0.4
nm/min



Absorption at Mn-L edge

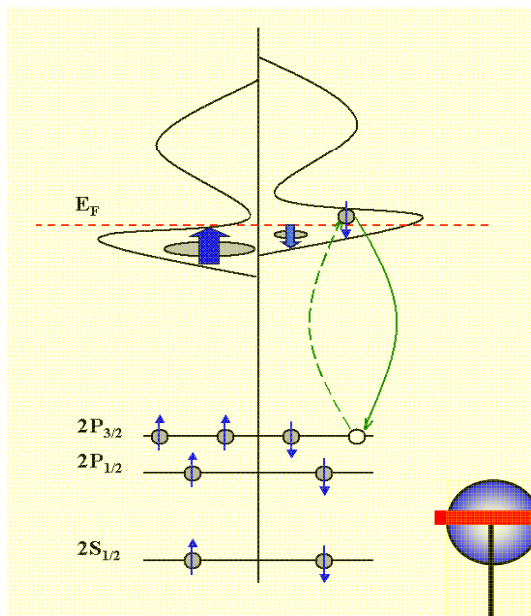


Probe of Orbital order: Resonant X-ray Scattering

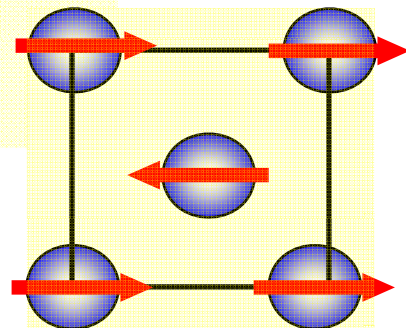
2nd order matrix element

$$\sum_I \frac{\langle f | \mathcal{K}' | I \rangle \langle I | \mathcal{K}' | i \rangle}{E_i - E_I} ; \mathcal{K}' = e\vec{r} \cdot \vec{E}$$

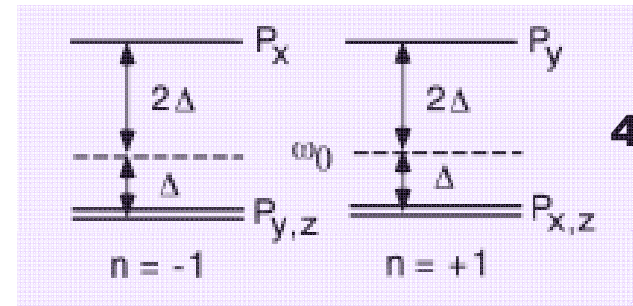
DOS energy



L-edge
 $2p \rightarrow 3d$

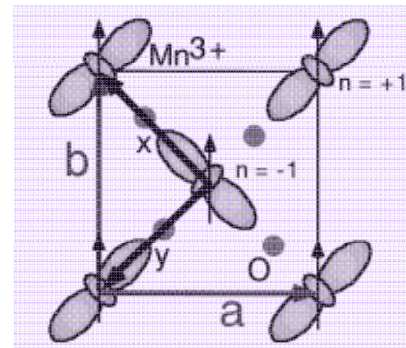


K-edge
 $1s \rightarrow 4p$



4p

1s



3d orbital

Scattering Length

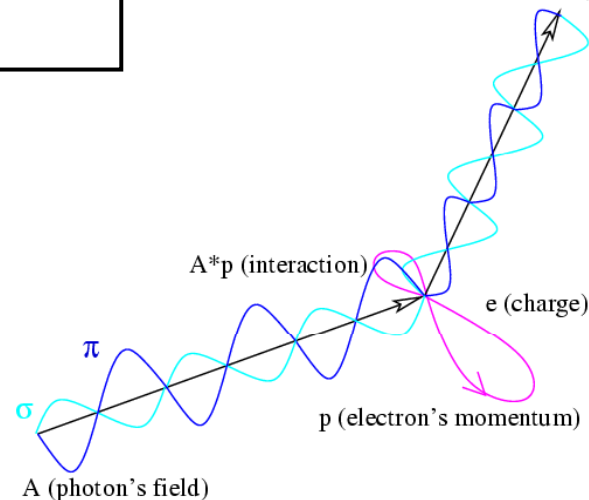
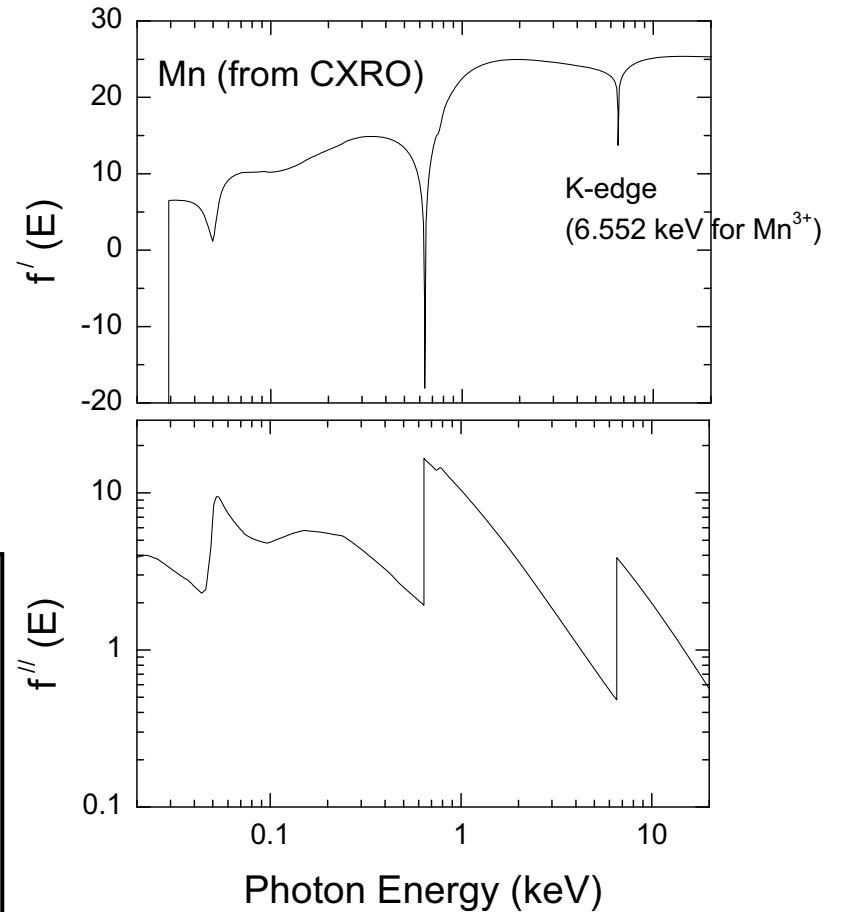
$$f = f^0(q) + f'(E) + i f''(E)$$

Thomson scattering

$q = 4 \pi \sin \theta / \lambda$
 $f^0(q)$ is the fourier transform of electric charge density.

Dispersion correction

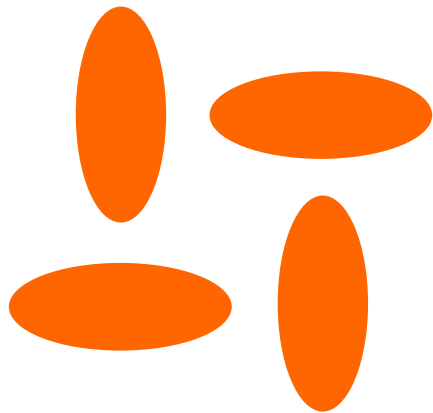
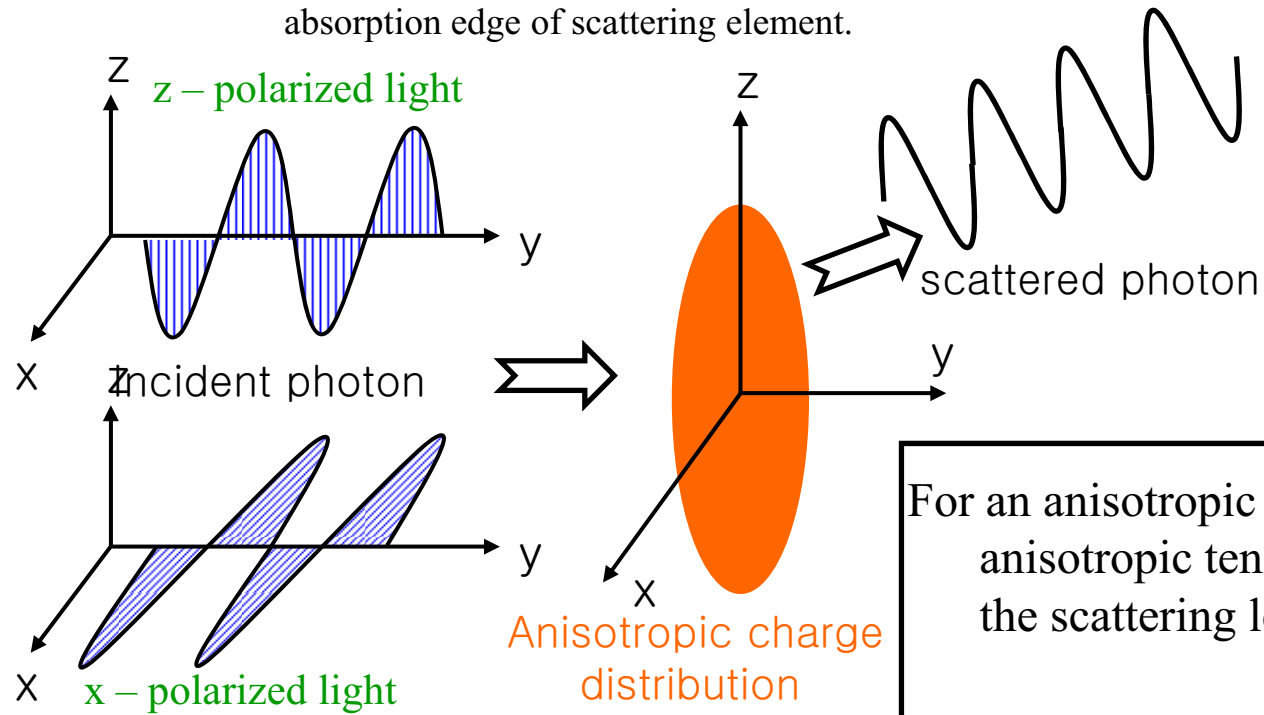
Resonant, however elastic scattering
 Classically, it is similar to the damped harmonic oscillator.
 Quantum mechanically, it is second order effect of dipole perturbation.
 (photon absorption and emission)
 Imaginary part is proportional to photo-absorption cross section and real part can be extracted from Kramers-kronig relation.



cf) B. E. Warren, X-ray diffraction
 Als-Nielsen and McMorrow, Elements
 of Modern X-ray Physics
 X-ray Data Booklet (CXRO)

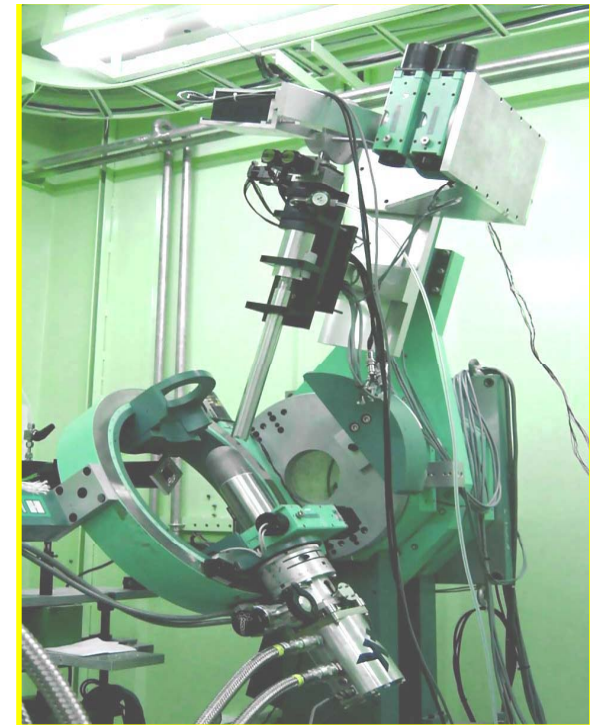
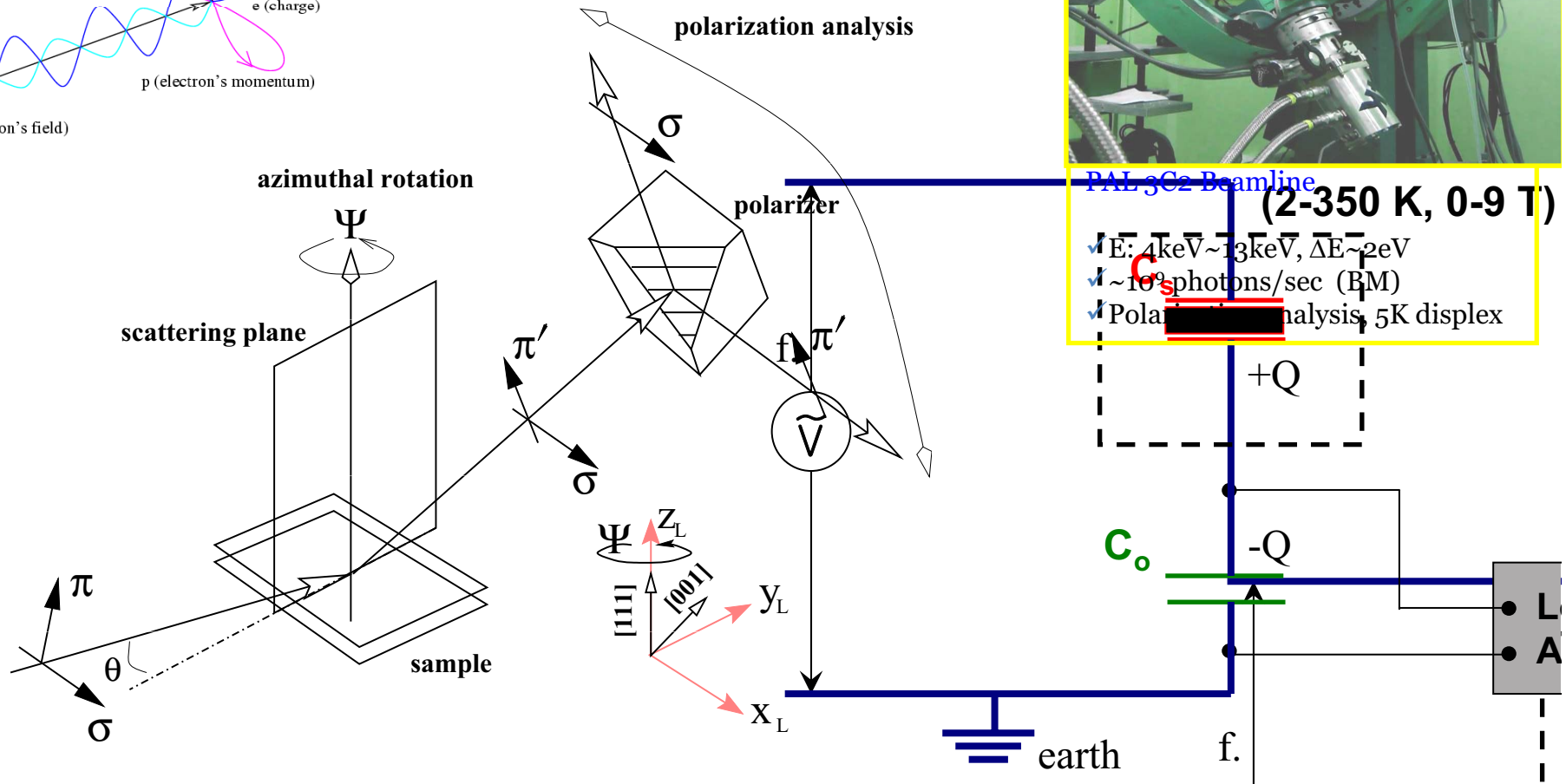
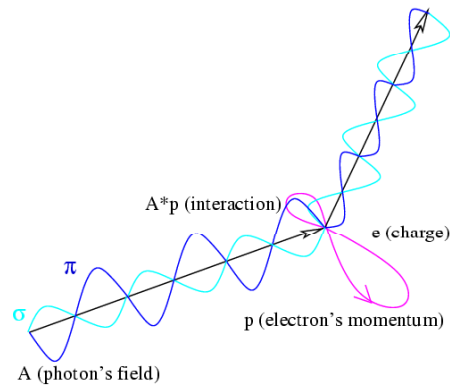
Why resonant scattering ?

Say, incident photon energy is tuned to absorption edge of scattering element.



Because of ATS, a superlattice peak may appear at a forbidden reciprocal position. This peak can be largely enhanced when incident photon energy is tuned to the absorption edge.

The experimental configuration for X-ray scattering



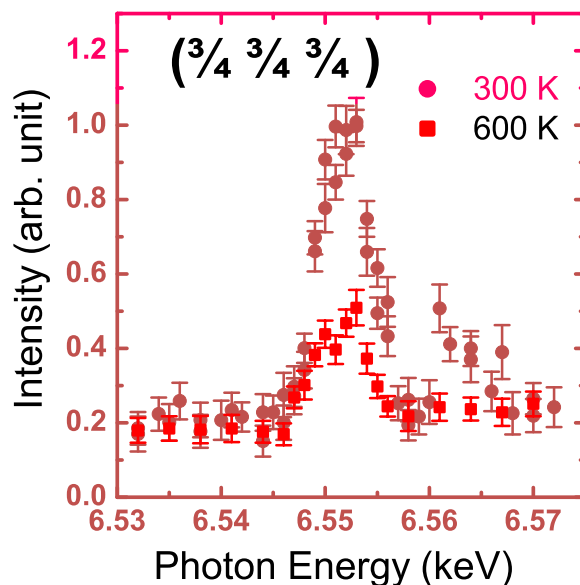
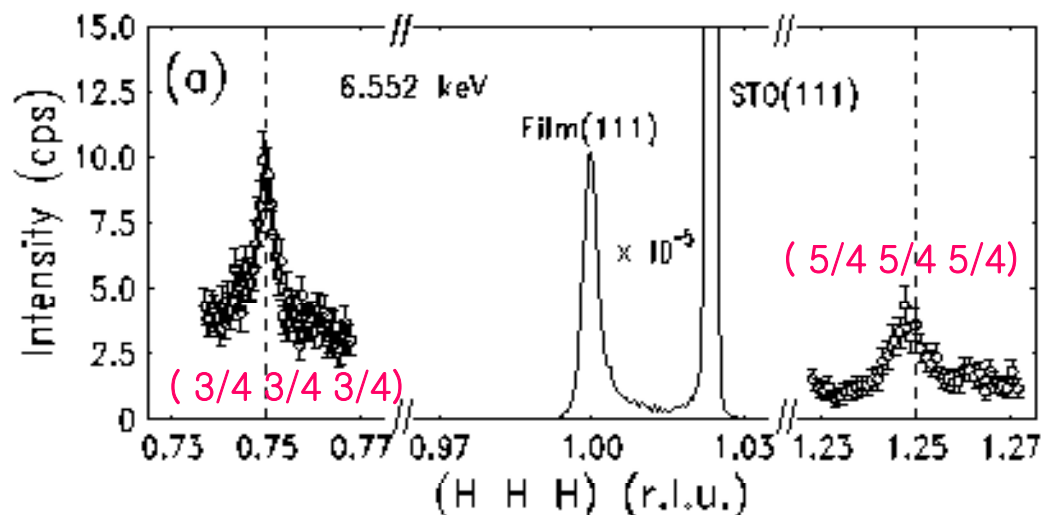
PAL 5C2 Beamline
(2-350 K, 0-9 T)

- ✓ $E: 4\text{keV} \sim 13\text{keV}, \Delta E \sim 2\text{eV}$
- ✓ $\sim 10^{19}$ photons/sec (BM)
- ✓ Polarization analysis, 5K displac

Resonant X-ray Scattering of BiMnO_3

grown on .05% Nb-doped
 $\text{SrTiO}_3(111)$ substrate

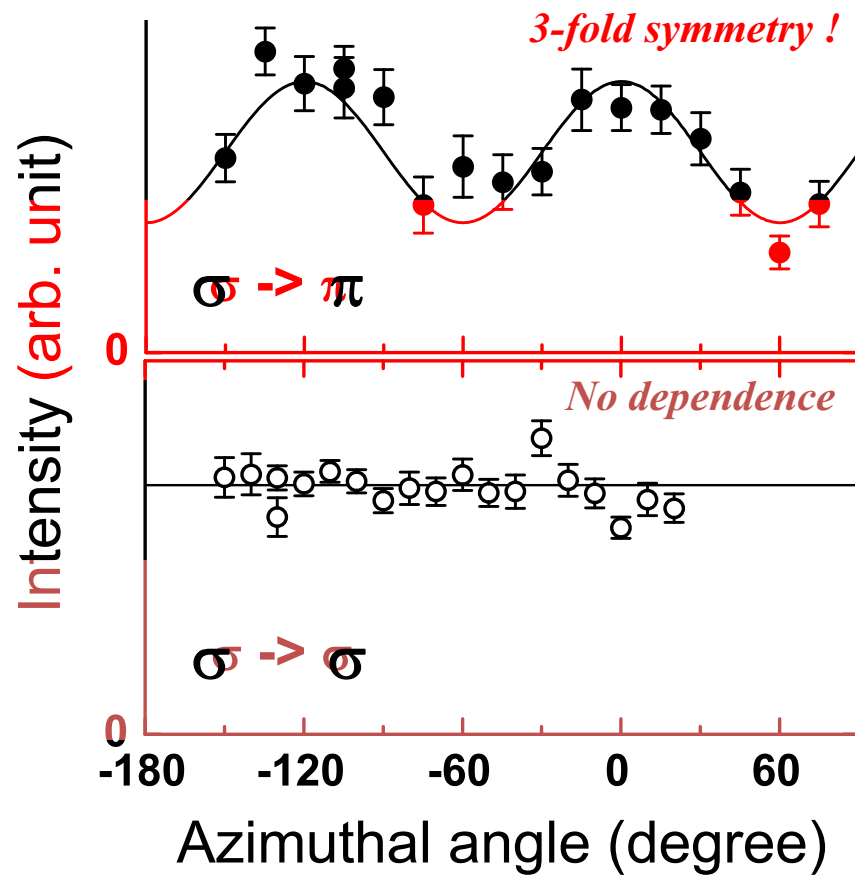
$d = 37 \text{ nm}$



The superlattice peak is enhanced at Mn^{3+} edge 6.552 keV.

Azimuthal dependence - RXS

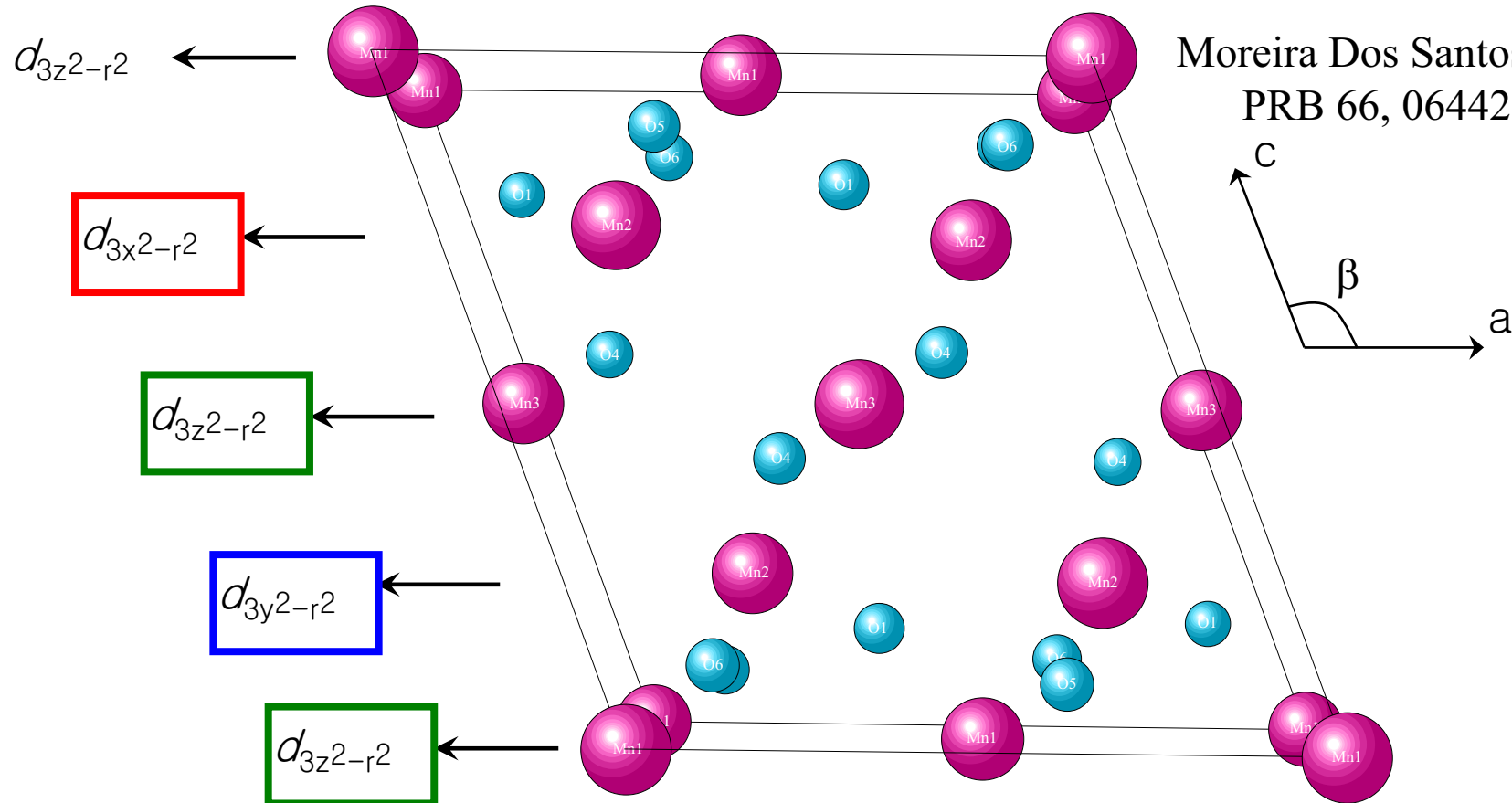
$(\frac{3}{4} \frac{3}{4} \frac{3}{4})$



Calculation : azimuthal angle dependence of orbital ordering peak

Space Group : $C2$

Moreira Dos Santos A.,
PRB 66, 064425 (2002)



Structure factor
for (00L)

$$2f_z e^0 + 2f_x e^{i2\pi Lz} + 2f_z e^{i2\pi L\frac{1}{2}} + 2f_y e^{-i2\pi Lz} + C(\text{Bi}) + C(\text{O})$$

$z = \frac{3}{4} + \Delta z \Rightarrow$ Charge scattering + Anomalous scattering

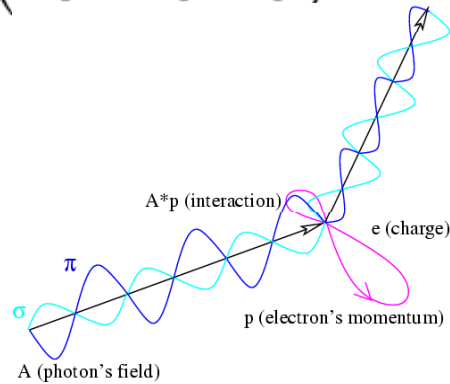
$$2f_z e^0 + 2f_x e^{i2\pi Lz} + 2f_z e^{i2\pi L\frac{1}{2}} + 2f_y e^{-i2\pi Lz} + C(\text{Bi}) + C(\text{O}) \quad (3.10)$$

$$\simeq 2(-1)^{\frac{L+1}{2}} i f_\Delta \begin{pmatrix} 1 & 0 & 0 \\ 0 & -1 & 0 \\ 0 & 0 & 0 \end{pmatrix} + 4(f_{Mn} + f_\perp) \cos 2\pi Lz + C(\text{Bi}) + C(\text{O}),$$

$$\mathcal{F}_{res}^{\alpha\beta} = \sum_{m=x,y,z} \frac{\langle 1s | P^\alpha | 4p_m \rangle \langle 4p_m | P^\beta | 1s \rangle}{\omega - \omega_0 - \delta\omega_m + i\Gamma/2}$$

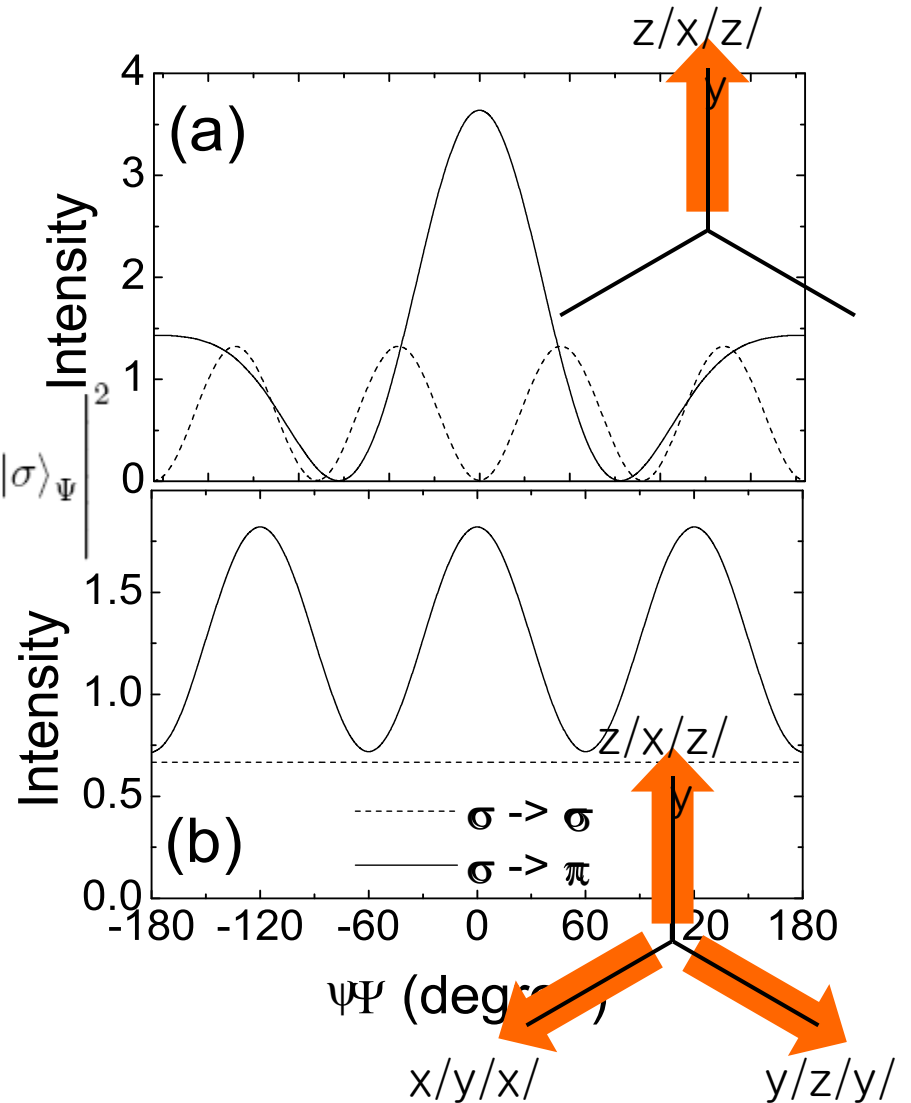
$$\mathbf{F}_{res} = \begin{pmatrix} f_\perp & 0 & 0 \\ 0 & f_\perp & 0 \\ 0 & 0 & f_\parallel \end{pmatrix}$$

$$I_{\sigma \rightarrow \sigma, \pi} = \left| \langle \sigma, \pi | \Psi \mathcal{M}_{L \rightarrow B}^\dagger \begin{pmatrix} 2f_\Delta & 0 & 0 \\ 0 & -2f_\Delta & 0 \\ 0 & 0 & 0 \end{pmatrix} \mathcal{M}_{L \rightarrow B} | \sigma \rangle \Psi \right|^2$$

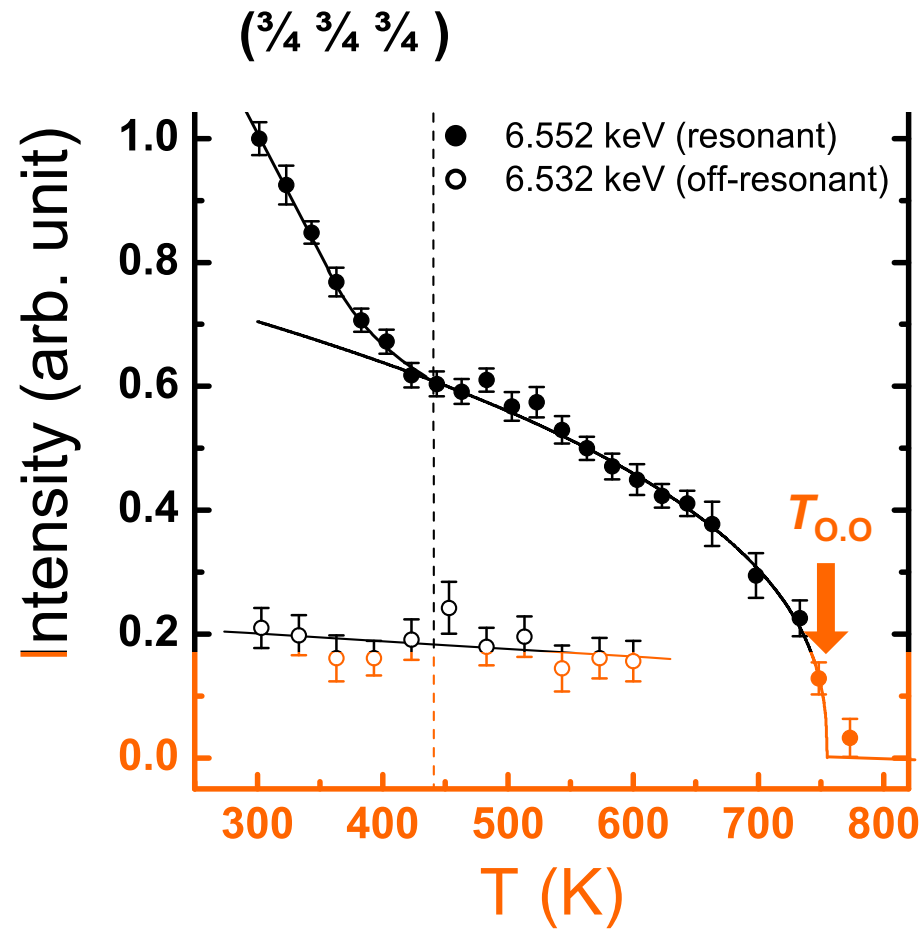


$$I_{\sigma \rightarrow \sigma} = \frac{4}{3} f_\Delta^2 \sin^2 2\Psi,$$

$$I_{\sigma \rightarrow \pi} = \frac{4}{3} f_\Delta^2 (\sqrt{2} \cos \theta \cos \Psi + \cos 2\Psi \sin \theta)^2$$



Temperature dependence of orbital order



The peak persists up to 770 K and shows an anomaly around 440 K.

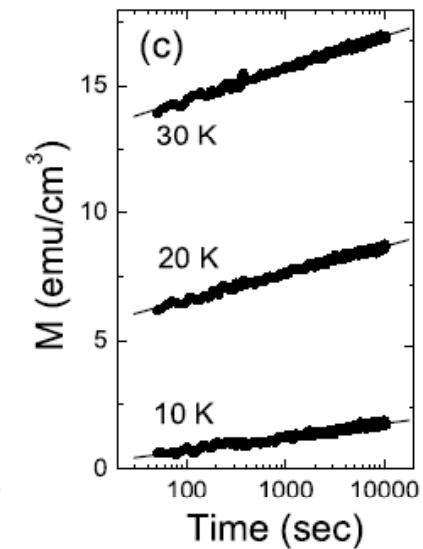
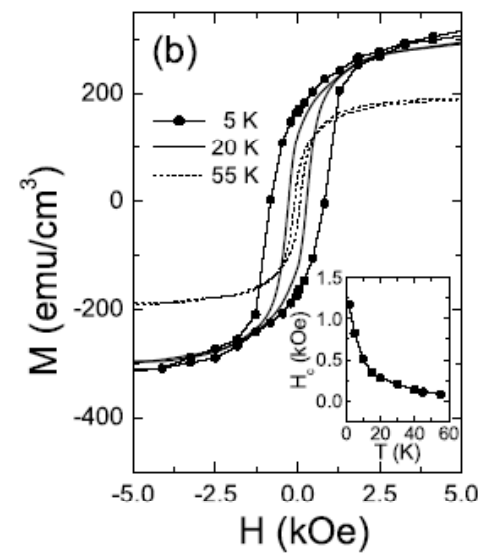
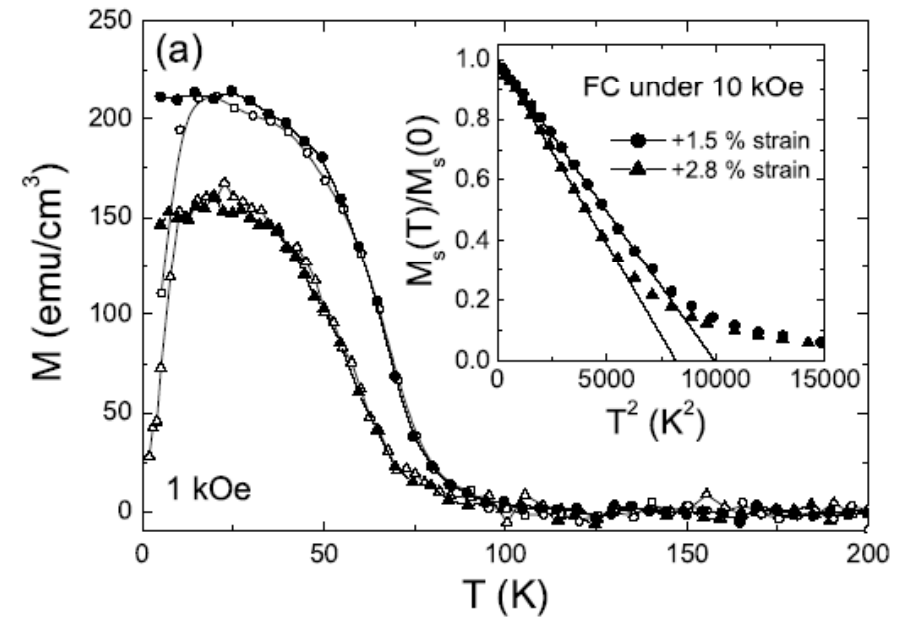
Magnetic consequences

Unusual magnetic properties
“cluster glass like behaviors”

- FC & ZFC $M(T)$
- H_c
- relaxation
- T^2 law



caused by frustration
stemming from peculiar
Orbital Ordering in BMO.



Modifying BiMnO_3

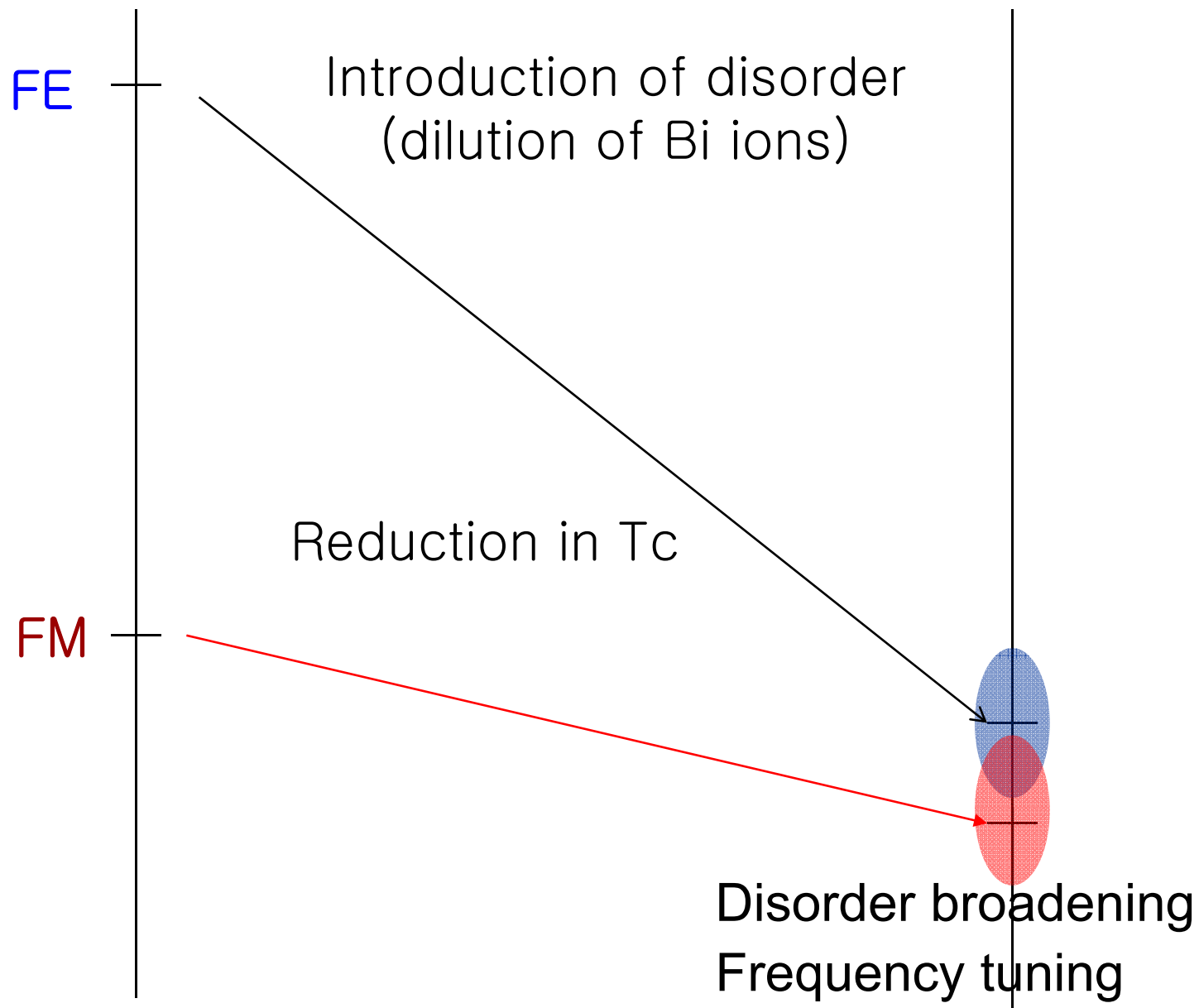
Two observations:

- The transition temperatures are in strong disparity.

One type of order develops in the presence of the other order already fully saturated.

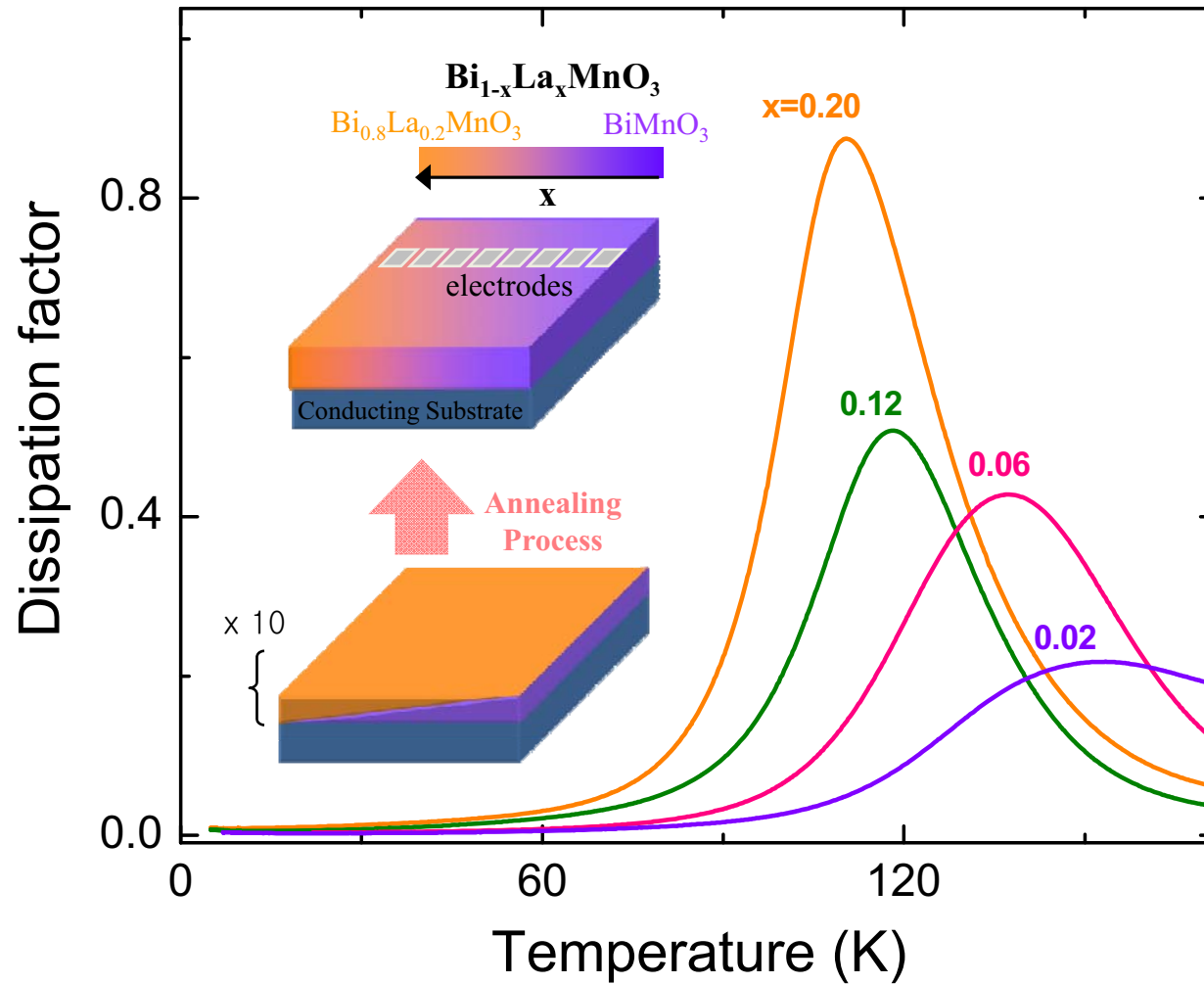
- Susceptibilities become large in transition regions.

Overlapping of the two transitions would lead to amplification effects.

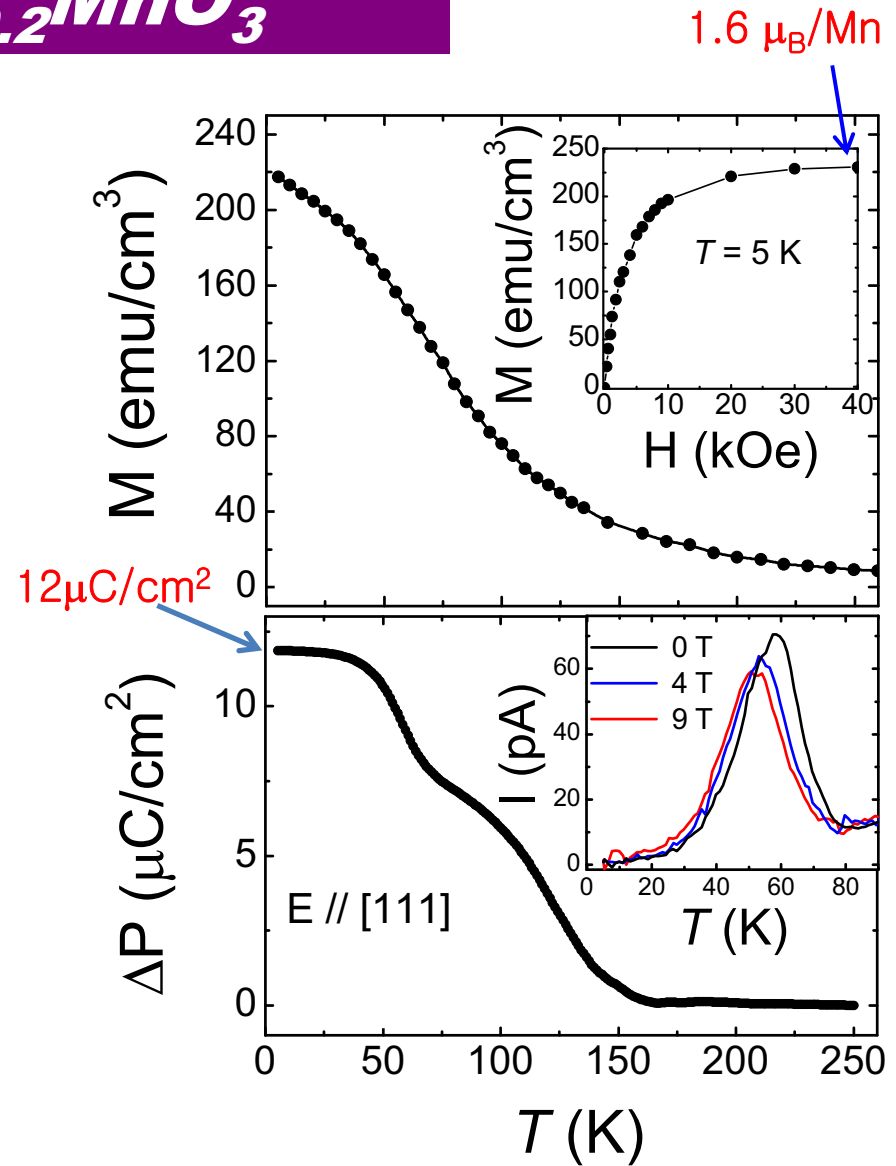
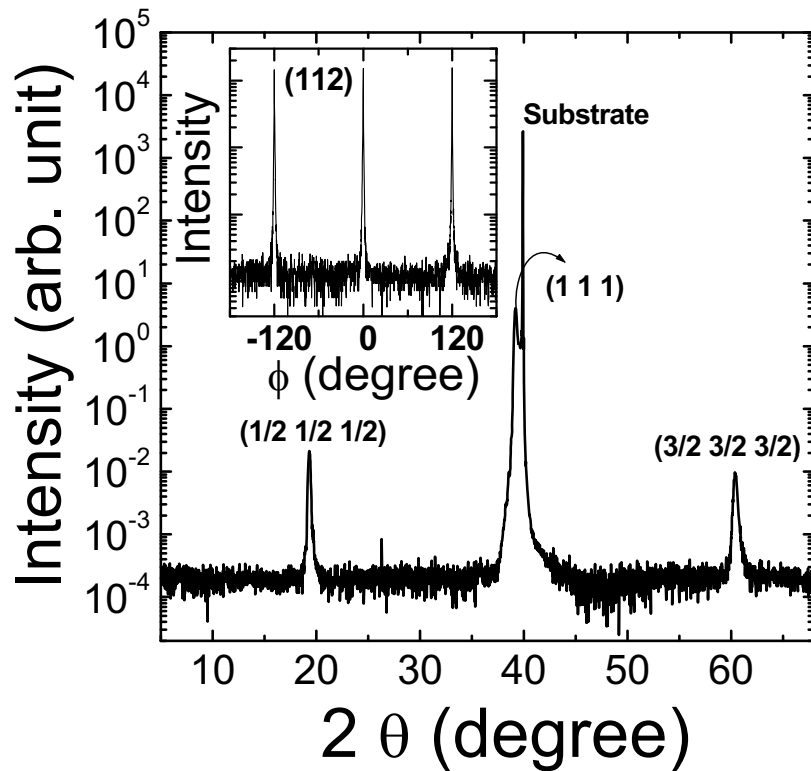


La doping via combinatorial chemistry

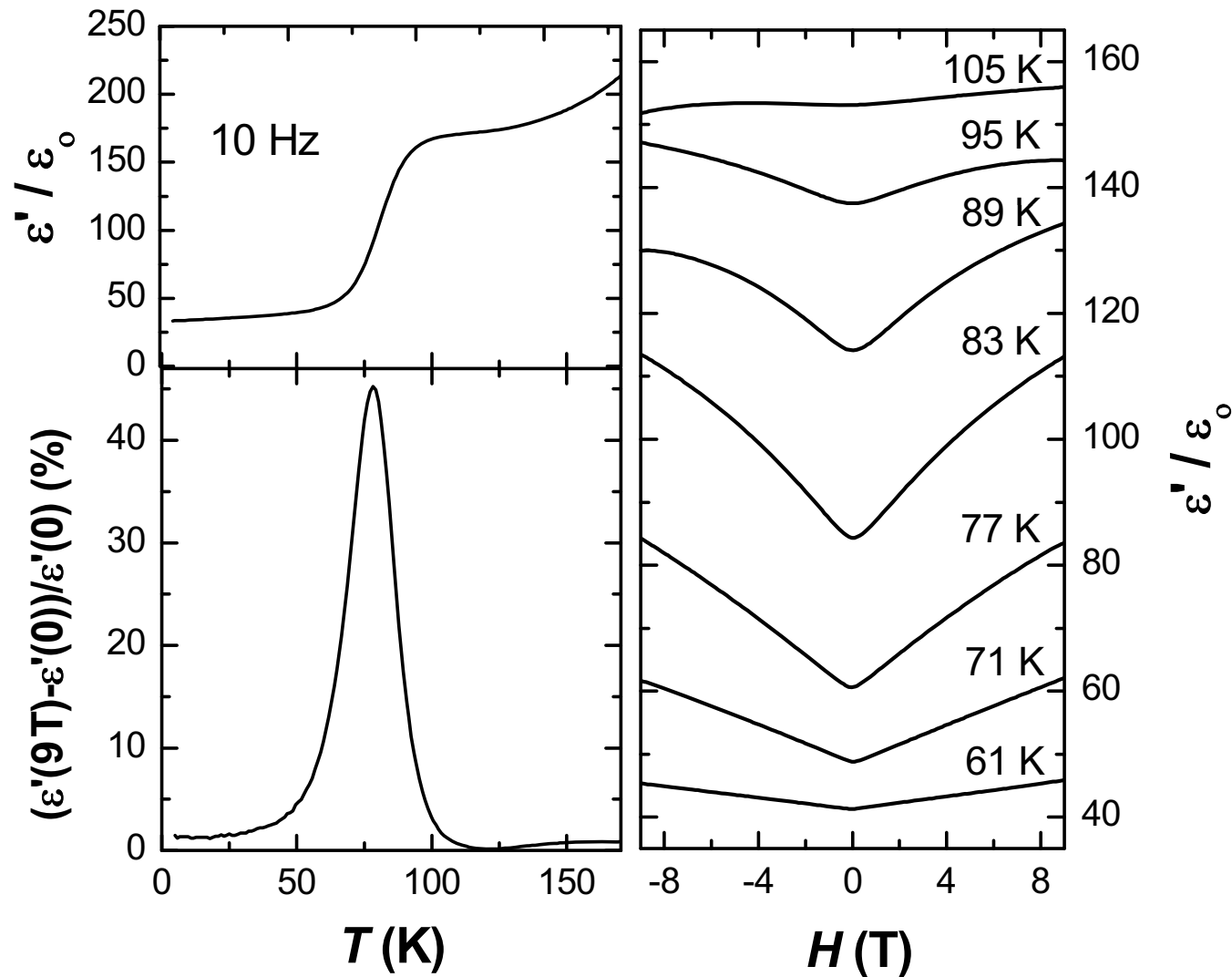
Dielectric properties



Structure and Magnetization & Polarization of $\text{Bi}_{0.8}\text{La}_{0.2}\text{MnO}_3$

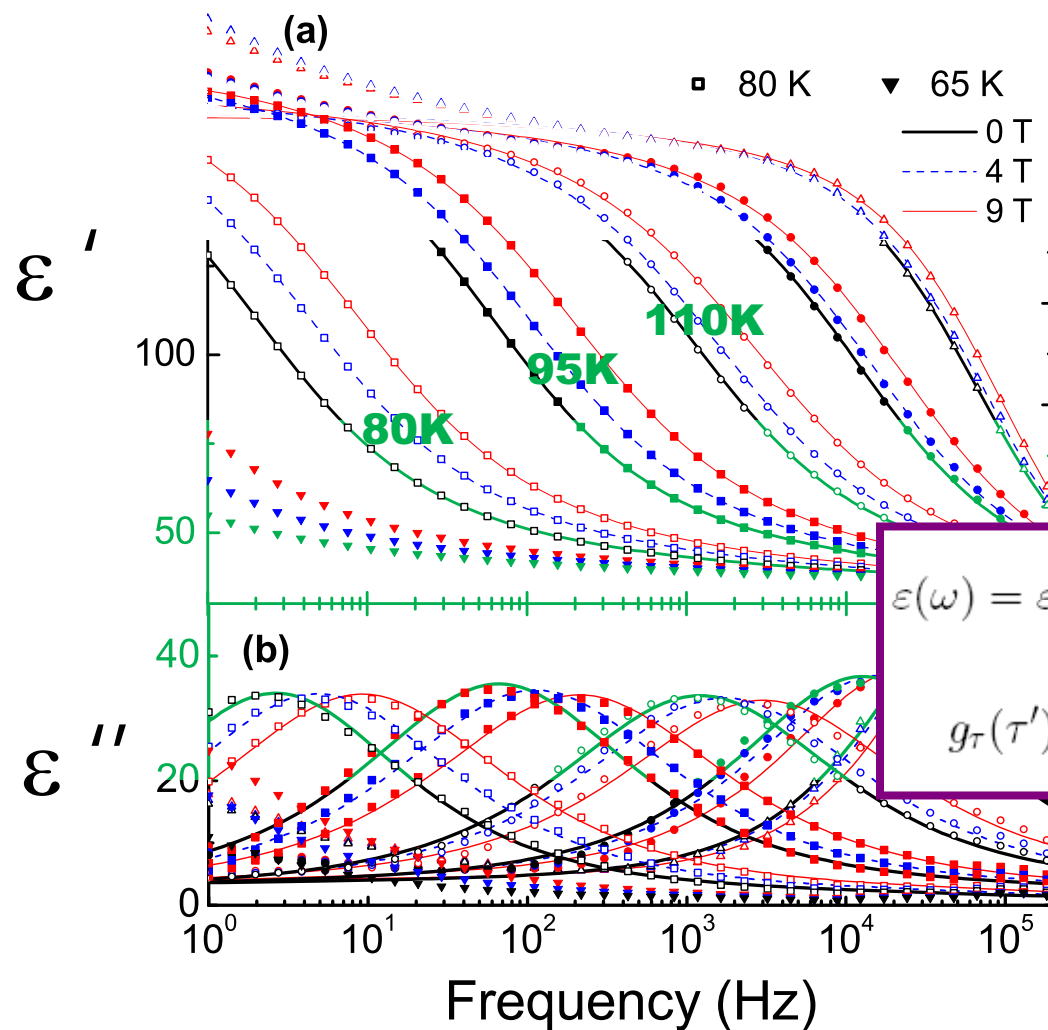


Large Magnetodielectric Effect



$\Delta\epsilon/\epsilon = 45\%$ at 80 K is a 70-fold increase from -0.6% of BiMnO_3

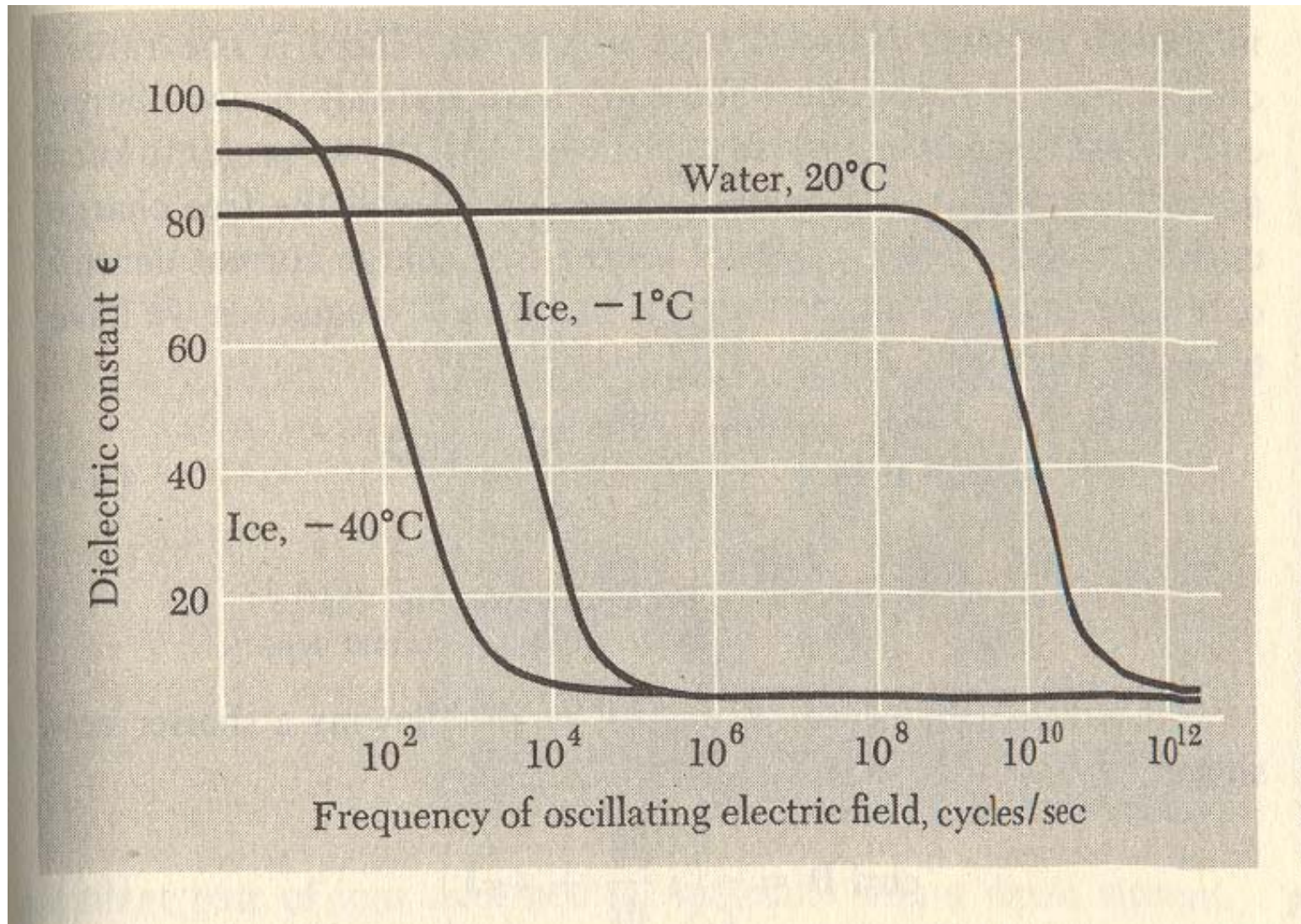
Controlling electric relaxation with a magnetic field

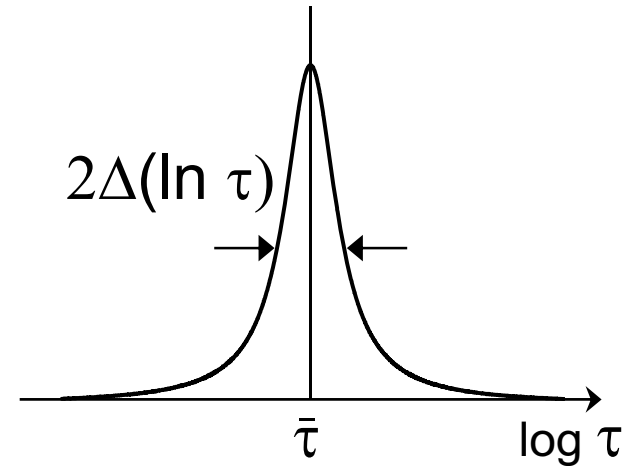
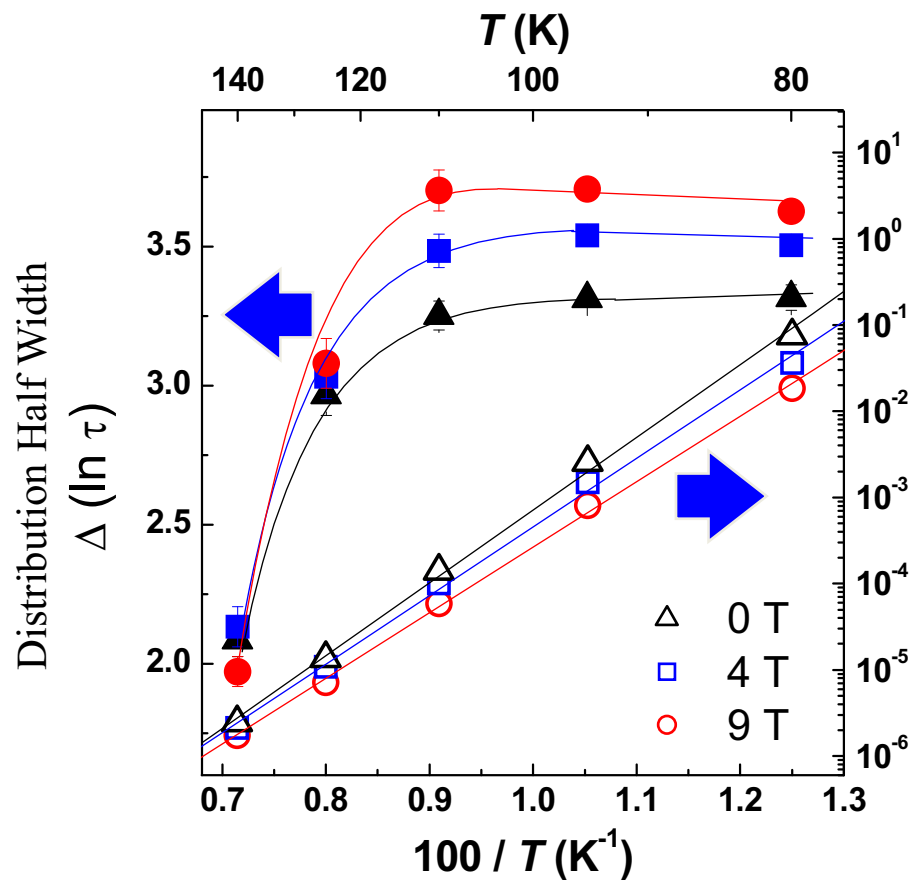


$$\epsilon(\omega) = \epsilon_0 + (\epsilon_\infty - \epsilon_0) \int \frac{1}{1 + i \omega \tau'} \frac{g_\tau(\tau')}{\tau'} d\tau',$$

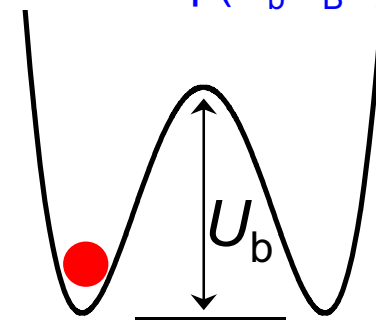
$$g_\tau(\tau') = \frac{\Delta(\ln(\tau))/2\pi}{(\ln(\tau') - \ln(\tau))^2 + \Delta(\ln(\tau))^2},$$

Dielectric relaxation in water



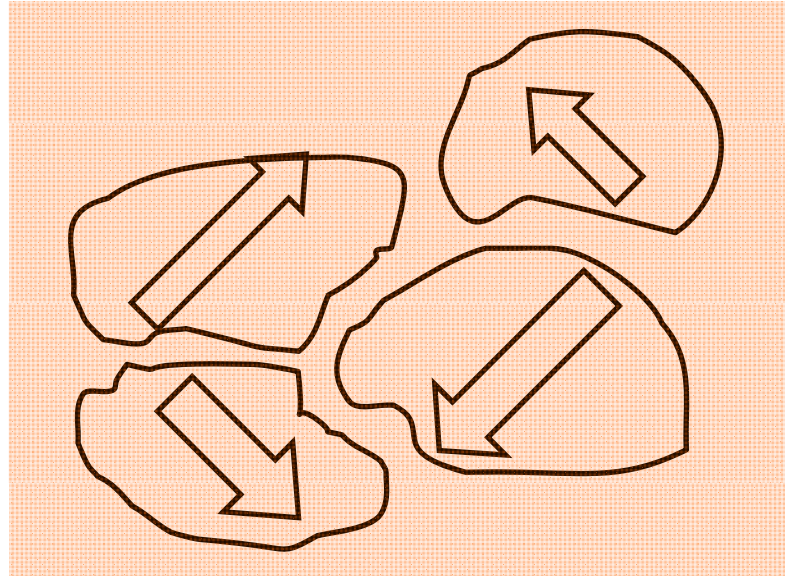


$$1/\tau = \exp(U_b/k_B T)$$



U_b depends on H field.

- 162 meV for 0T
- 153 meV for 4T
- 146 meV for 9T



Conclusions and outlook

We have revealed the orbital order and its magnetic consequences in pure BiMnO₃, and also demonstrated the possibility of tailoring the properties of BiMnO₃ compounds.

Currently work is in progress:

- (1) elucidation of low temperature FM and FE structures**
- (2) development of multiferroic materials with room temperature or higher transition temperatures.**

No impurities and high crystallinity

